



# Vincotech

<b>flowPIM 1 + PFC</b>		<b>650 V / 40 A</b>
<b>Topology features</b>		
<ul style="list-style-type: none"><li>• Converter+Brake+Inverter</li><li>• Open Emitter configuration</li><li>• Temperature sensor</li></ul>		
<b>Component features</b>		<b>flow 1 12 mm housing</b>
<ul style="list-style-type: none"><li>• Easy paralleling</li><li>• Low collector emitter saturation voltage</li><li>• Low turn-off losses</li><li>• Positive temperature coefficient</li></ul>		
<b>Housing features</b>		
<ul style="list-style-type: none"><li>• Base isolation: Al<sub>2</sub>O<sub>3</sub></li><li>• Convex shaped substrate for superior thermal contact</li><li>• Thermo-mechanical push-and-pull force relief</li><li>• Press-fit pin</li><li>• Reliable cold welding connection</li></ul>		
<b>Target applications</b>		<b>Schematic</b>
<ul style="list-style-type: none"><li>• Embedded Drives</li><li>• Heat Pumps</li><li>• HVAC</li><li>• Industrial Drives</li></ul>		
<b>Types</b>		
<ul style="list-style-type: none"><li>• 10-PY07PMA040I7-P585B68Y</li></ul>		



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Inverter Switch</b>				
Collector-emitter voltage	$V_{CES}$		650	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	45	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	120	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	65	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ , $V_{CC} = 400\text{ V}$ $T_j = 150^\circ\text{C}$	3	$\mu\text{s}$
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Inverter Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	38	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	120	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	54	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$
<b>Brake Switch</b>				
Collector-emitter voltage	$V_{CES}$		650	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	45	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	120	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	65	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ , $V_{CC} = 400\text{ V}$ $T_j = 150^\circ\text{C}$	3	$\mu\text{s}$
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$



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## Maximum Ratings

$T_j = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Brake Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	22	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	60	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	34	W
Maximum junction temperature	$T_{jmax}$		175	$^\circ\text{C}$

## Rectifier Diode

Peak repetitive reverse voltage	$V_{RRM}$		1600	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	52	A
Surge (non-repetitive) forward current	$I_{FSM}$	Single Half Sine Wave, $t_p = 10 \text{ ms}$	400	A
Surge current capability	$I^t$	$T_j = 150^\circ\text{C}$	800	$\text{A}^2\text{s}$
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	59	W
Maximum junction temperature	$T_{jmax}$		150	$^\circ\text{C}$

## Module Properties

Thermal Properties				
Storage temperature	$T_{stg}$		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	$T_{jop}$		-40...+( $T_{jmax} - 25$ )	$^\circ\text{C}$

## Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
Creepage distance				>12,7	mm
Clearance				8,34	mm
Comparative Tracking Index	CTI			$\geq 200$	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

## Inverter Switch

## Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0004	25	4,35	5	5,65	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		40	25 125 150		1,29 1,35 1,37	1,65 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25			20	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			100	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{res}$	$f = 1 \text{ MHz}$	0	25	25	25	2475		pF	
Output capacitance	$C_{ces}$									
Reverse transfer capacitance	$C_{res}$									
Gate charge	$Q_g$	$V_{CC} = 520 \text{ V}$	15		40	25		235		nC

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2 \text{ W/mK}$ (PTM)						1,46		K/W
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## Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	$-5/15$	$350$	$40$	25		23,25		
Rise time	$t_r$					125		26,16		ns
						150		26,34		
Turn-off delay time	$t_{d(off)}$					25		8,38		
						125		9,51		
Fall time	$t_f$					150		9,63		ns
Turn-on energy (per pulse)	$E_{on}$	$Q_{fFWD}=1,05 \mu\text{C}$ $Q_{rFWD}=2,04 \mu\text{C}$ $Q_{tFWD}=2,37 \mu\text{C}$				25		117,32		
						125		143,52		
Turn-off energy (per pulse)	$E_{off}$					150		149,94		ns
						25		24,19		
						125		39,19		
						150		45,49		ns
						25		0,17		
						125		0,263		
						150		0,298		mWs
						25		0,622		
						125		0,875		
						150		0,963		mWs



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## Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max

## Inverter Diode

## Static

Forward voltage	$V_F$				40	25 125 150		1,62 1,52 1,49	2 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 650$ V			25			20	$\mu$ A	

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						1,74		K/W
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## Dynamic

Peak recovery current	$I_{RM}$	$di/dt=4691$ A/ $\mu$ s $di/dt=4505$ A/ $\mu$ s $di/dt=4493$ A/ $\mu$ s	-5/15	350	40	25 125 150		49,55 61,87 66,22		A
Reverse recovery time	$t_{rr}$					25 125 150		50,94 82,42 92,37		ns
Recovered charge	$Q_r$					25 125 150		1,05 2,04 2,37		$\mu$ C
Reverse recovered energy	$E_{rec}$					25 125 150		0,306 0,588 0,682		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		2555,19 2000,21 2092,57		A/ $\mu$ s



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

## Brake Switch

## Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0004	25	4,35	5	5,65	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		40	25 125 150		1,29 1,35 1,37	1,65 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25			20	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			100	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{res}$	$f = 1 \text{ MHz}$	0	25	25	25	2475		pF	
Output capacitance	$C_{ces}$									
Reverse transfer capacitance	$C_{res}$									
Gate charge	$Q_g$	$V_{CC} = 520 \text{ V}$	15		40	25		235		nC

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2 \text{ W/mK}$ (PTM)						1,46		K/W
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## Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	0/15	400	40	25		19,72	ns	
Rise time	$t_r$					125		20,62		
						150		20,73		
Turn-off delay time	$t_{d(off)}$					25		15,03		
						125		15,91		
Fall time	$t_f$					150		16,08		
Turn-on energy (per pulse)	$E_{on}$	$Q_{tFWD}=0,713 \mu\text{C}$ $Q_{tFWD}=1,48 \mu\text{C}$ $Q_{tFWD}=1,73 \mu\text{C}$				25		134,47	ns	
						125		166		
						150		174,29		
Turn-off energy (per pulse)	$E_{off}$					25		19,97	ns	
						125		38,16		
						150		43,15		
						25		0,654	mWs	
						125		0,863		
						150		0,91		
						25		0,658	mWs	
						125		1		
						150		1,11		



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## Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max

## Brake Diode

## Static

Forward voltage	$V_F$				20	25 125 150		1,71 1,6 1,55	2 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 650$ V			25			20	$\mu$ A	

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						2,81		K/W
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## Dynamic

Peak recovery current	$I_{RM}$	$di/dt=1357$ A/ $\mu$ s $di/dt=1469$ A/ $\mu$ s $di/dt=1545$ A/ $\mu$ s	0/15	400	40	25 125 150		14,08 20,35 21,7		A
Reverse recovery time	$t_{rr}$					25 125 150		91,01 133,87 147,9		ns
Recovered charge	$Q_r$					25 125 150		0,713 1,48 1,73		$\mu$ C
Reverse recovered energy	$E_{rec}$					25 125 150		0,195 0,432 0,509		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		429,19 228,53 210,47		A/ $\mu$ s



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## Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		$V_{GE}$ [V]	$V_{GS}$ [V]	$V_{CE}$ [V]	$V_{DS}$ [V]	$I_C$ [A]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max

## Rectifier Diode

## Static

Forward voltage	$V_F$				35	25 125 150		1,09 1,03 1,02	1,5 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 1600$ V				25 150			100 2000	$\mu$ A

## Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						1,19		K/W
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## Thermistor

## Static

Rated resistance	$R$					25		22		$k\Omega$
Deviation of R100	$A_{R/R}$	$R_{100} = 1484$ $\Omega$				100	-5		5	%
Power dissipation	$P$					25		130		$mW$
Power dissipation constant	$d$					25		1,5		$mW/K$
B-value	$B_{(25/50)}$	Tol. $\pm 1$ %						3962		K
B-value	$B_{(25/100)}$	Tol. $\pm 1$ %						4000		K
Vincotech Thermistor Reference									I	

<sup>(1)</sup> Value at chip level<sup>(2)</sup> Only valid with pre-applied Vincotech thermal interface material.



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## Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$

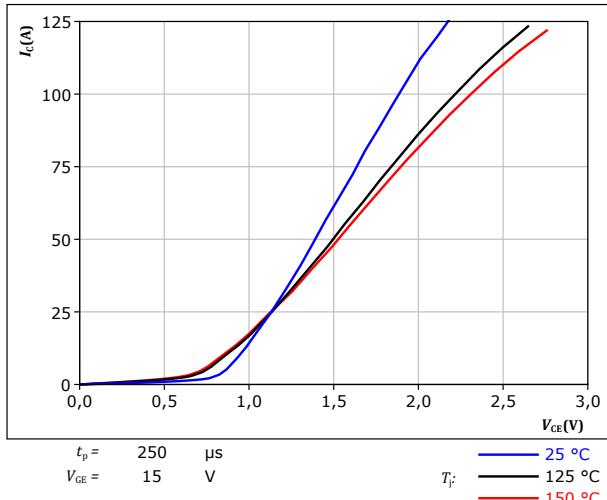


figure 2. IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$

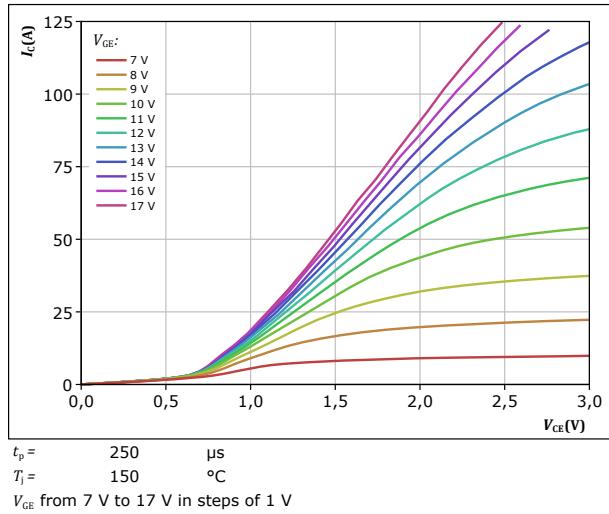


figure 3. IGBT

Typical transfer characteristics  
 $I_C = f(V_{GE})$

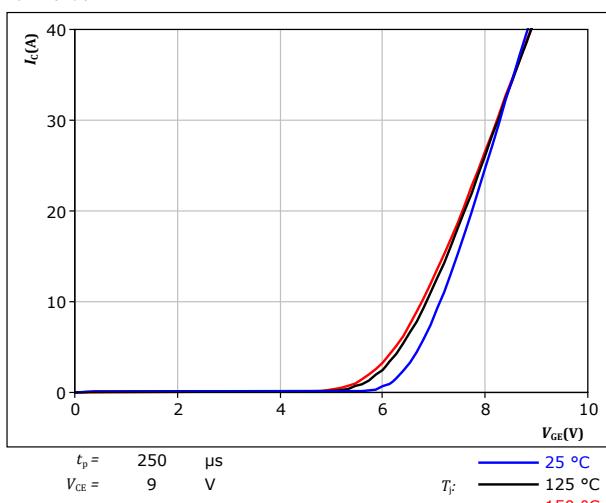
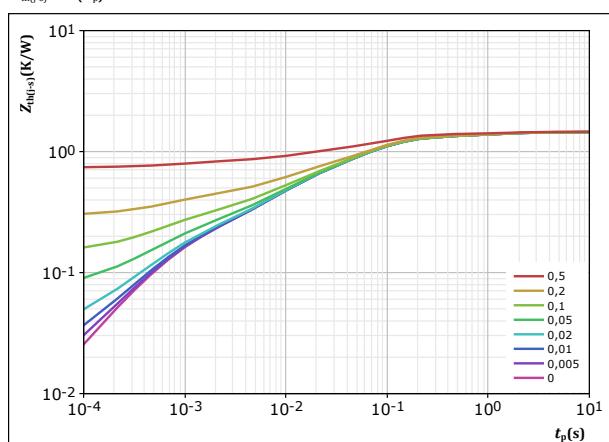


figure 4. IGBT

Transient thermal impedance as a function of pulse width  
 $Z_{th(j-s)} = f(t_p)$

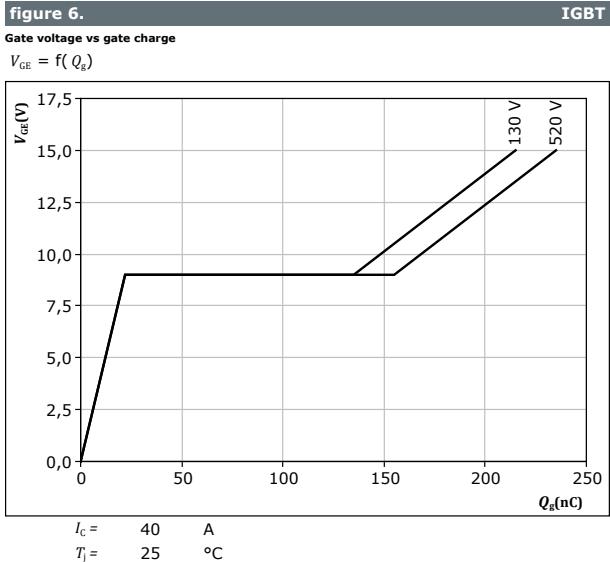
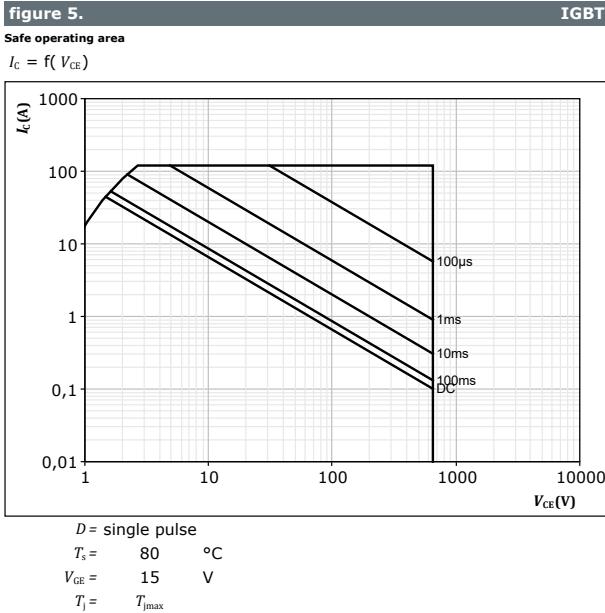


$R$ (K/W)	$\tau$ (s)
2,96E-02	4,18E+01
1,52E-01	1,05E+00
8,10E-01	7,07E-02
3,29E-01	9,38E-03
1,52E-01	6,80E-04



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## Inverter Switch Characteristics





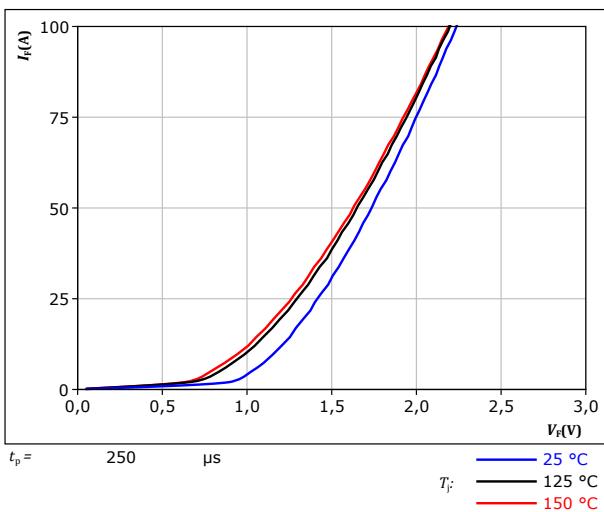
## Inverter Diode Characteristics

figure 7.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

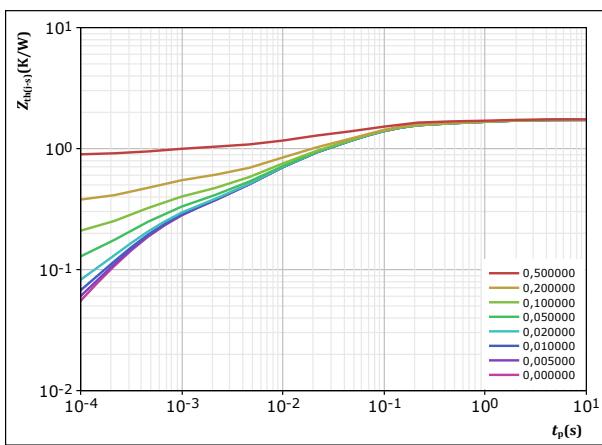
$$T_F: \begin{array}{ll} \text{---} & 25^\circ\text{C} \\ \text{—} & 125^\circ\text{C} \\ \text{—} & 150^\circ\text{C} \end{array}$$

figure 8.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

FWD



$$D = \frac{t_p}{T} = 1,745$$

K/W

FWD thermal model values

$R$ (K/W)	$\tau$ (s)
4,17E-02	1,05E+02
1,71E-01	9,20E-01
8,24E-01	6,43E-02
4,91E-01	8,28E-03
2,37E-01	4,41E-04



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## Brake Switch Characteristics

figure 9. IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$

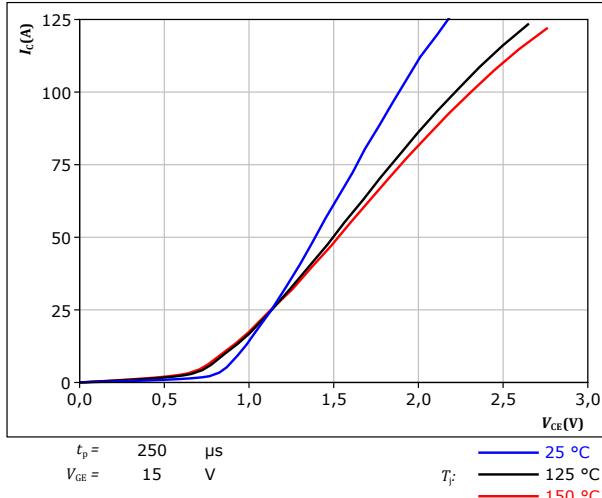


figure 10. IGBT

Typical output characteristics  
 $I_C = f(V_{CE})$

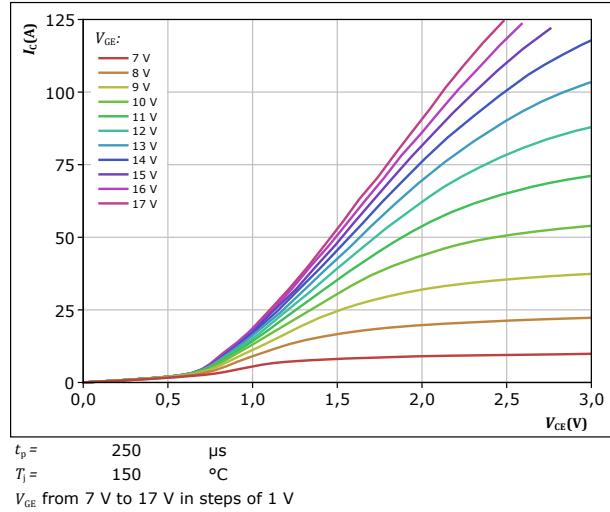


figure 11. IGBT

Typical transfer characteristics  
 $I_C = f(V_{GE})$

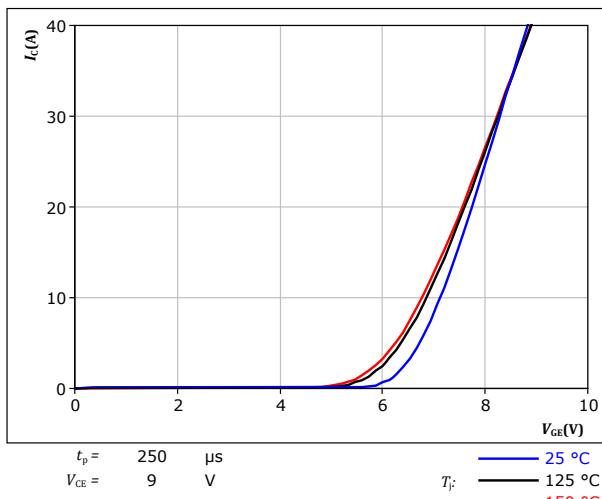
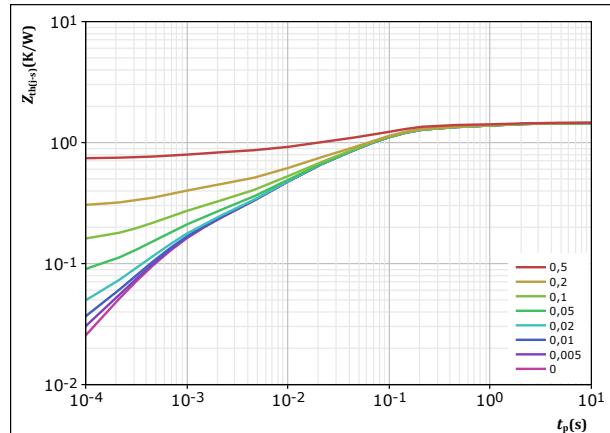


figure 12. IGBT

Transient thermal impedance as a function of pulse width

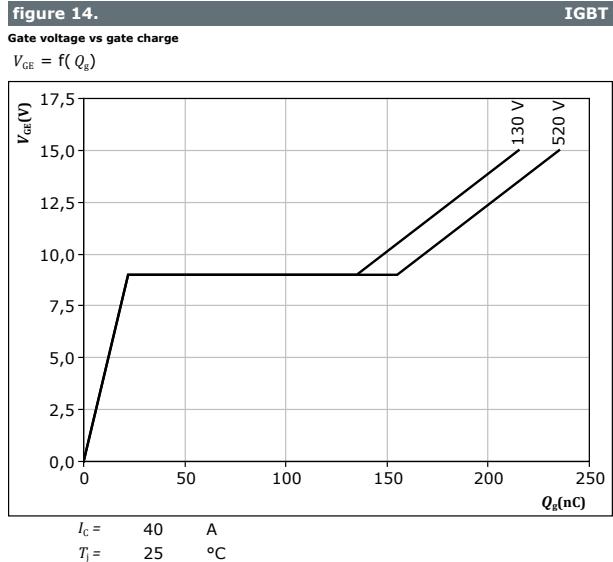
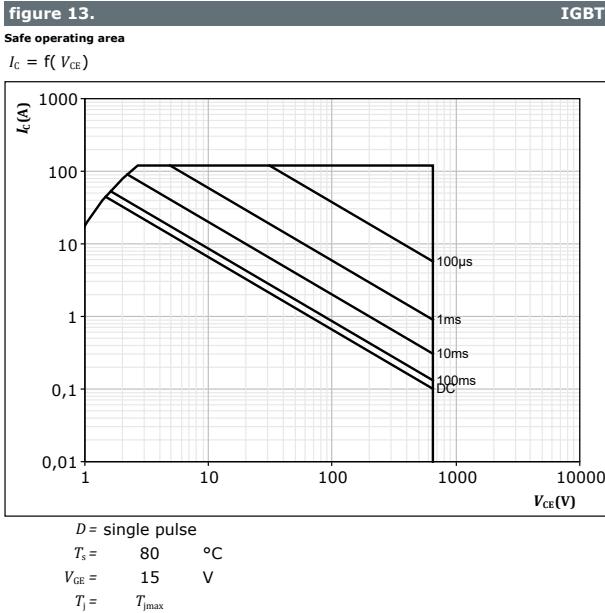
$Z_{th(j-s)} = f(t_p)$





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## Brake Switch Characteristics





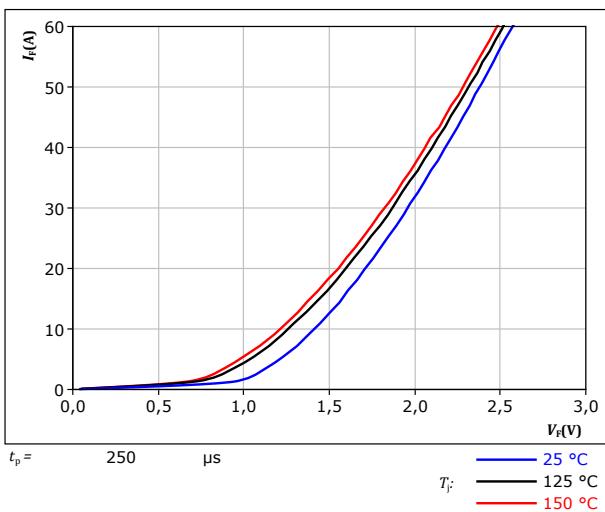
## Brake Diode Characteristics

figure 15.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

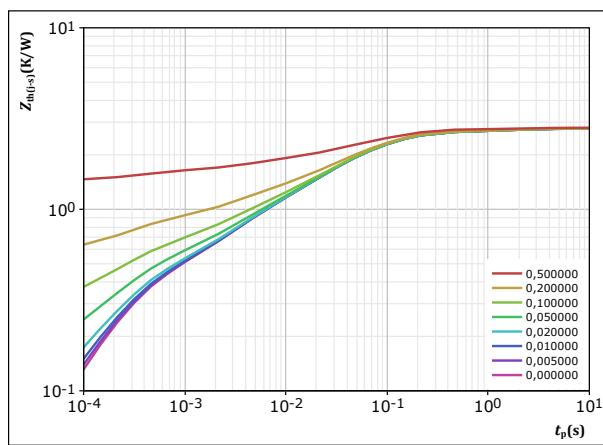
$$T_F: \quad \begin{array}{l} \text{---} 25^\circ\text{C} \\ \text{—} 125^\circ\text{C} \\ \text{—} 150^\circ\text{C} \end{array}$$

figure 16.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

FWD



$$D = \frac{t_p / \tau}{2,815} \quad \text{K/W}$$

FWD thermal model values

$R(K/W)$	$\tau(s)$
7,42E-02	8,84E+01
1,46E-01	1,38E+00
1,05E+00	9,07E-02
8,03E-01	2,22E-02
4,24E-01	3,02E-03
3,53E-01	2,60E-04



## Rectifier Diode Characteristics

figure 17.

Typical forward characteristics

$$I_F = f(V_F)$$

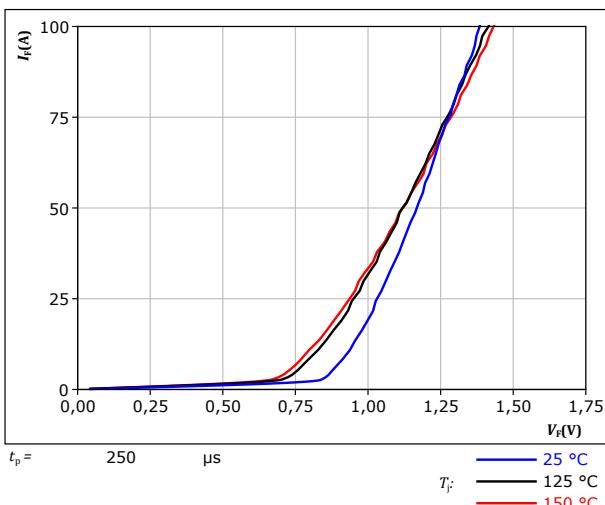
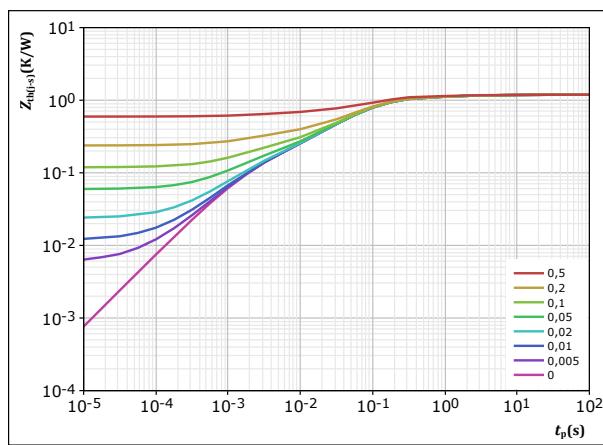


figure 18.

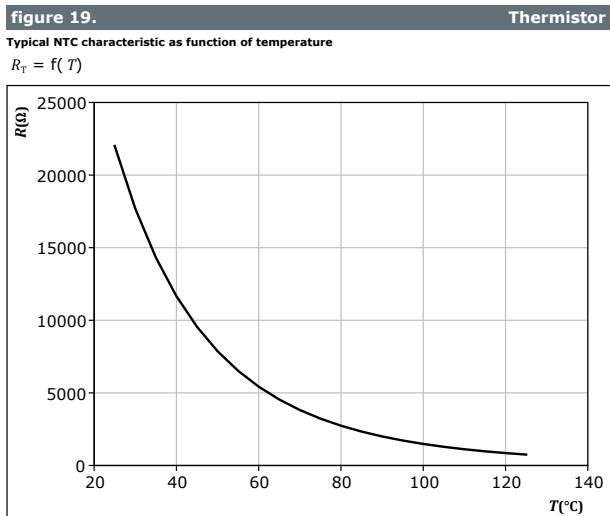
Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





## Thermistor Characteristics





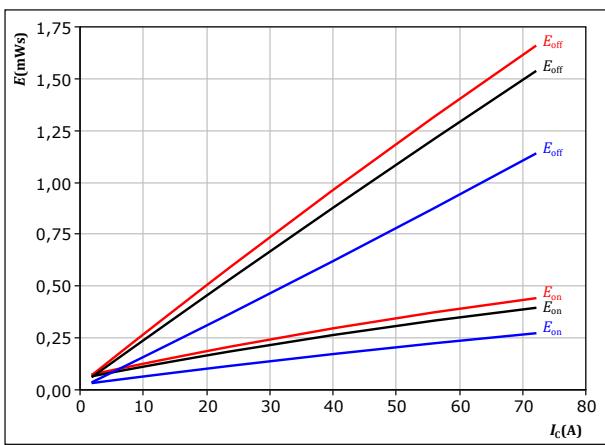
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## Inverter Switching Characteristics

figure 20.

IGBT

Typical switching energy losses as a function of collector current  
 $E = f(I_c)$



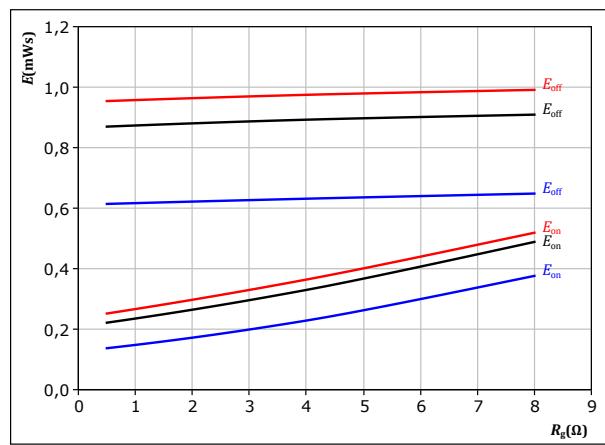
With an inductive load at

$V_{CE} = 350 \text{ V}$        $T_f: \quad 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $125^\circ\text{C}$   
 $R_{gon} = 2 \Omega$        $150^\circ\text{C}$   
 $R_{goff} = 2 \Omega$

figure 21.

IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor  
 $E = f(R_g)$



With an inductive load at

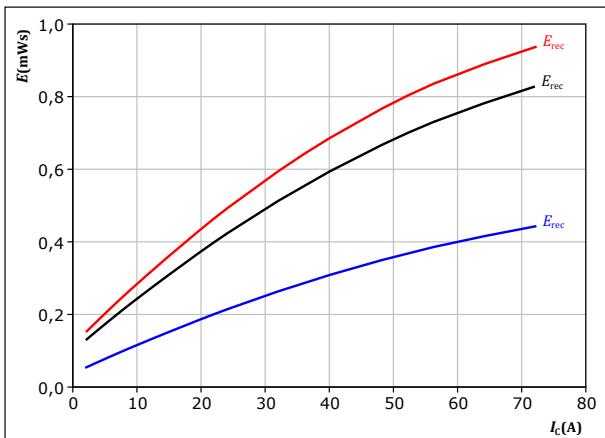
$V_{CE} = 350 \text{ V}$        $T_f: \quad 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $125^\circ\text{C}$   
 $I_c = 40 \text{ A}$        $150^\circ\text{C}$

figure 22.

FWD

Typical reverse recovered energy loss as a function of collector current

$E_{rec} = f(I_c)$



With an inductive load at

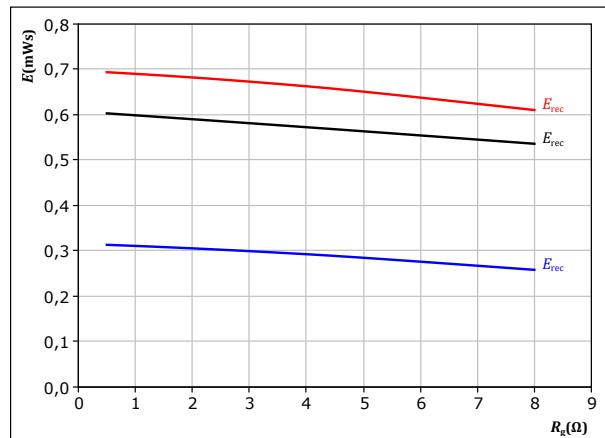
$V_{CE} = 350 \text{ V}$        $T_f: \quad 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $125^\circ\text{C}$   
 $R_{gon} = 2 \Omega$        $150^\circ\text{C}$

figure 23.

FWD

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$E_{rec} = f(R_g)$



With an inductive load at

$V_{CE} = 350 \text{ V}$        $T_f: \quad 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $125^\circ\text{C}$   
 $I_c = 40 \text{ A}$        $150^\circ\text{C}$

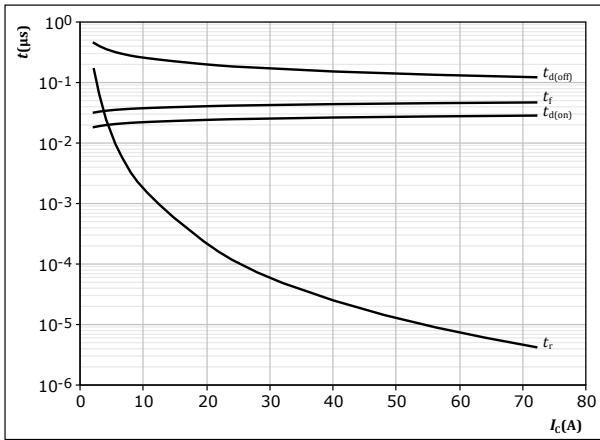


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## Inverter Switching Characteristics

figure 24. IGBT

Typical switching times as a function of collector current  
 $t = f(I_C)$

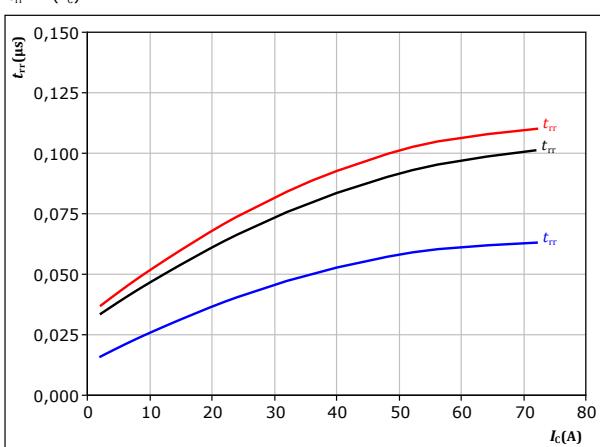


With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = -5/15 \text{ V}$   
 $R_{gon} = 2 \Omega$   
 $R_{goff} = 2 \Omega$

figure 26. FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_C)$

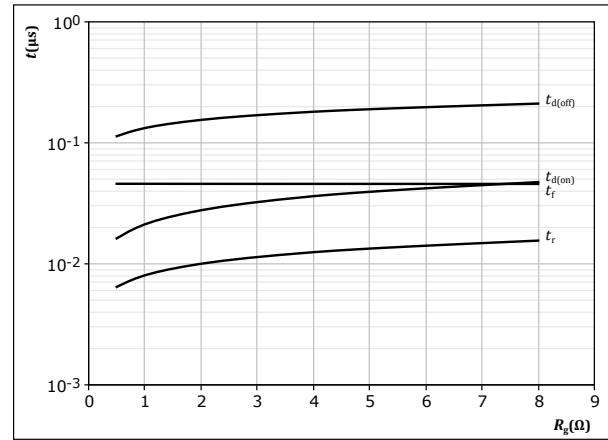


With an inductive load at

$V_{CE} = 350 \text{ V}$   
 $V_{GE} = -5/15 \text{ V}$   
 $R_{gon} = 2 \Omega$

figure 25. IGBT

Typical switching times as a function of IGBT turn on gate resistor  
 $t = f(R_g)$

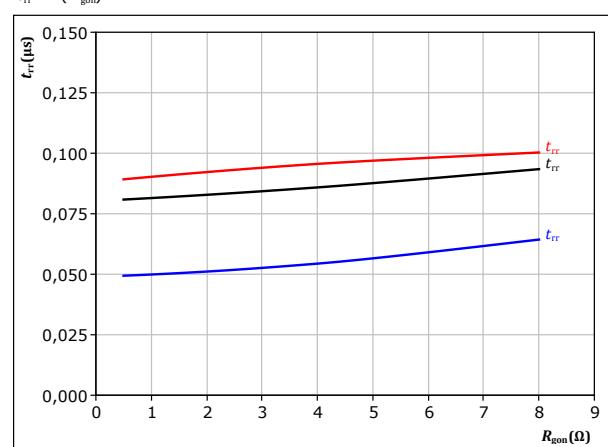


With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 350 \text{ V}$   
 $V_{GE} = -5/15 \text{ V}$   
 $I_C = 40 \text{ A}$

figure 27. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 350 \text{ V}$   
 $V_{GE} = -5/15 \text{ V}$   
 $I_C = 40 \text{ A}$



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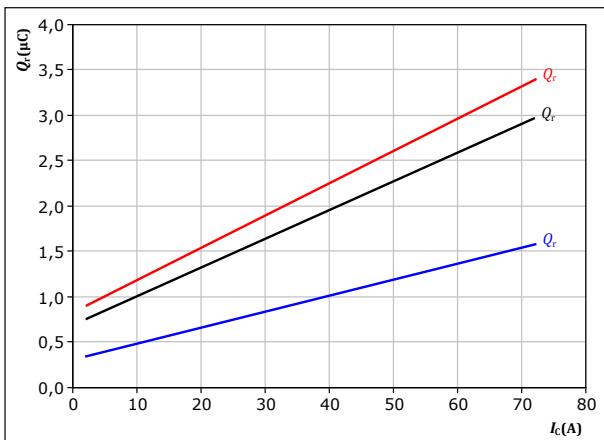
## Inverter Switching Characteristics

figure 28.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 350 \text{ V} \\ V_{GE} &= -5/15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

$$\begin{aligned} T_f &= 125 \text{ °C} \\ & \quad \text{---} \\ & \quad \text{---} \\ & \quad \text{---} \end{aligned}$$

$$25 \text{ °C}$$

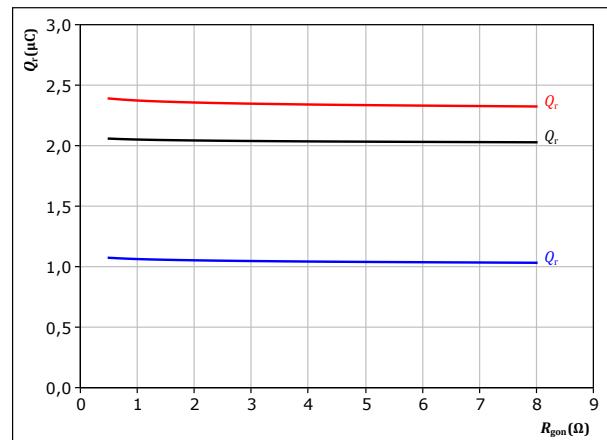
$$150 \text{ °C}$$

figure 29.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 350 \text{ V} \\ V_{GE} &= -5/15 \text{ V} \\ I_c &= 40 \text{ A} \end{aligned}$$

$$\begin{aligned} T_f &= 125 \text{ °C} \\ & \quad \text{---} \\ & \quad \text{---} \\ & \quad \text{---} \end{aligned}$$

$$25 \text{ °C}$$

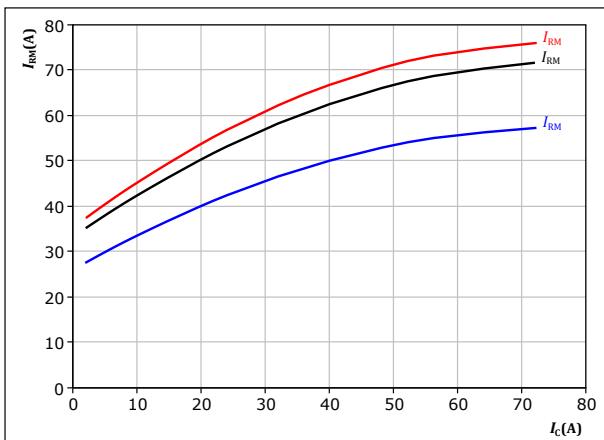
$$150 \text{ °C}$$

figure 30.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 350 \text{ V} \\ V_{GE} &= -5/15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

$$\begin{aligned} T_f &= 125 \text{ °C} \\ & \quad \text{---} \\ & \quad \text{---} \\ & \quad \text{---} \end{aligned}$$

$$25 \text{ °C}$$

$$150 \text{ °C}$$

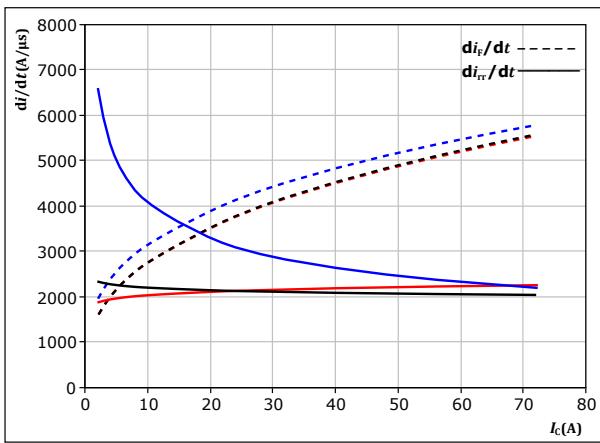


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## Inverter Switching Characteristics

figure 32. FWD

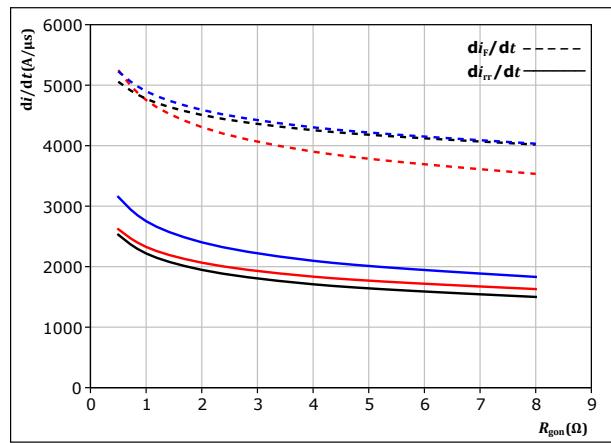
Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at  
 $V_{CE} = 350 \text{ V}$        $T_j = 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $T_j = 125^\circ\text{C}$   
 $R_{gon} = 2 \Omega$        $T_j = 150^\circ\text{C}$

figure 33. FWD

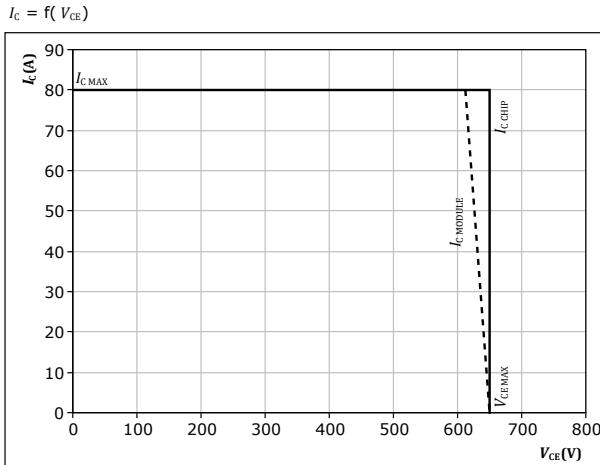
Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at  
 $V_{CE} = 350 \text{ V}$        $T_j = 25^\circ\text{C}$   
 $V_{GE} = -5/15 \text{ V}$        $T_j = 125^\circ\text{C}$   
 $I_c = 40 \text{ A}$        $T_j = 150^\circ\text{C}$

figure 34. IGBT

Reverse bias safe operating area  
 $I_c = f(V_{CE})$



At       $T_j = 150^\circ\text{C}$   
 $R_{gon} = 2 \Omega$   
 $R_{goff} = 2 \Omega$



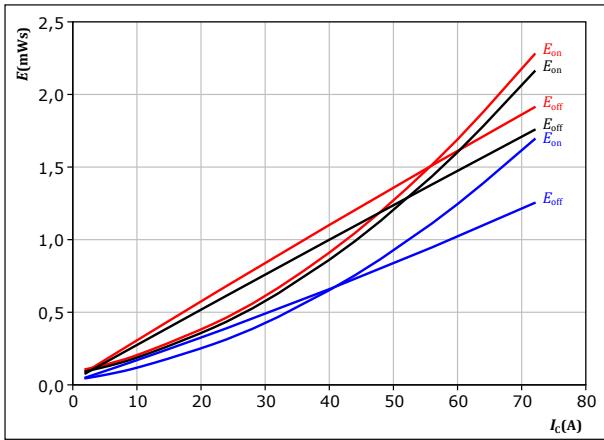
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## Brake Switching Characteristics

figure 35.

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$

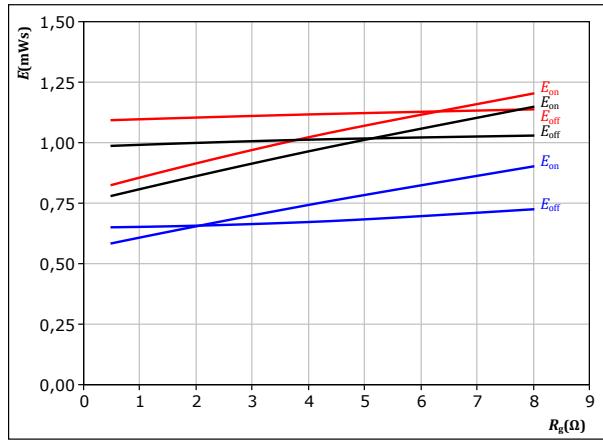


IGBT

figure 36.

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$

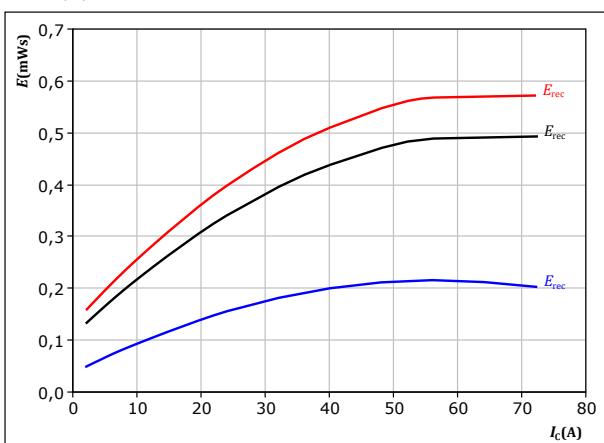


IGBT

figure 37.

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$

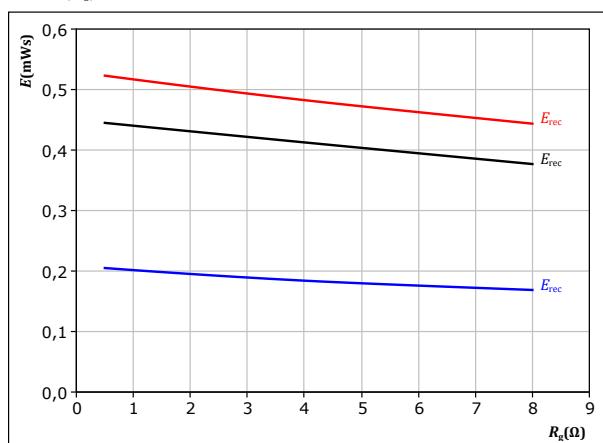


FWD

figure 38.

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



FWD

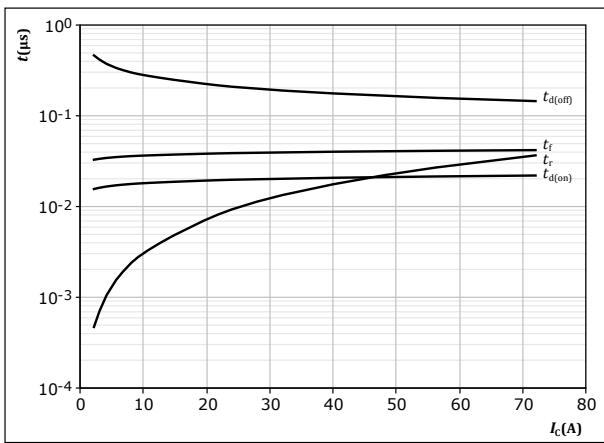


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## Brake Switching Characteristics

figure 39.

Typical switching times as a function of collector current  
 $t = f(I_C)$



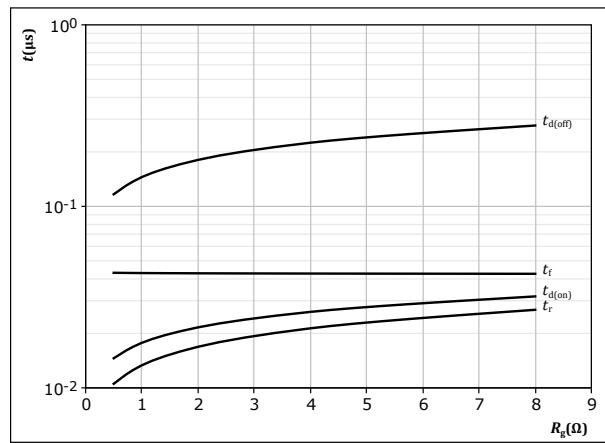
With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 400\text{ V}$   
 $V_{GE} = 0/15\text{ V}$   
 $R_{gon} = 2\Omega$   
 $R_{goff} = 2\Omega$

IGBT

figure 40.

Typical switching times as a function of IGBT turn on gate resistor  
 $t = f(R_g)$



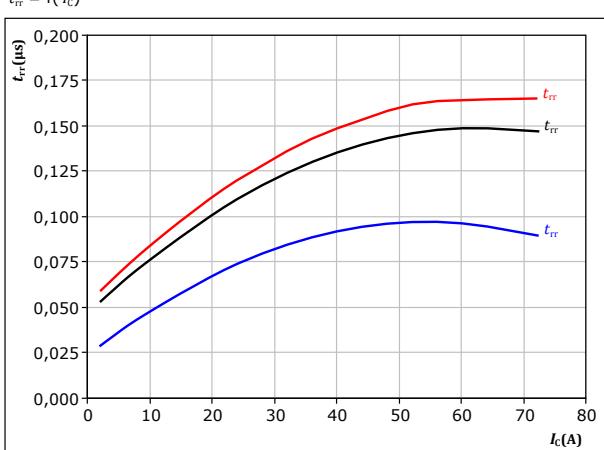
With an inductive load at

$T_j = 150^\circ\text{C}$   
 $V_{CE} = 400\text{ V}$   
 $V_{GE} = 0/15\text{ V}$   
 $I_C = 40\text{ A}$

IGBT

figure 41.

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_C)$



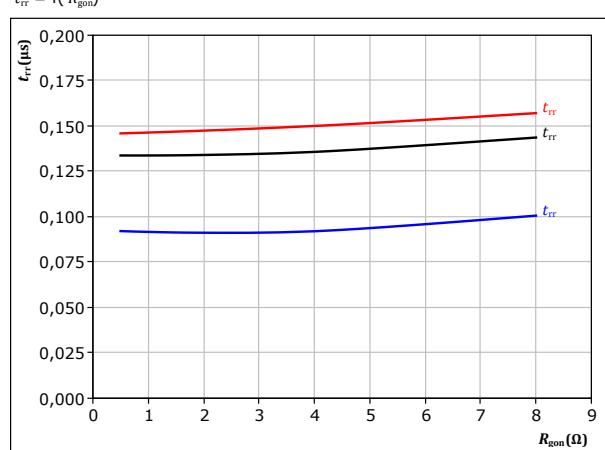
With an inductive load at

$V_{CE} = 400\text{ V}$   
 $V_{GE} = 0/15\text{ V}$   
 $R_{gon} = 2\Omega$

FWD

figure 42.

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 400\text{ V}$   
 $V_{GE} = 0/15\text{ V}$   
 $I_C = 40\text{ A}$

FWD



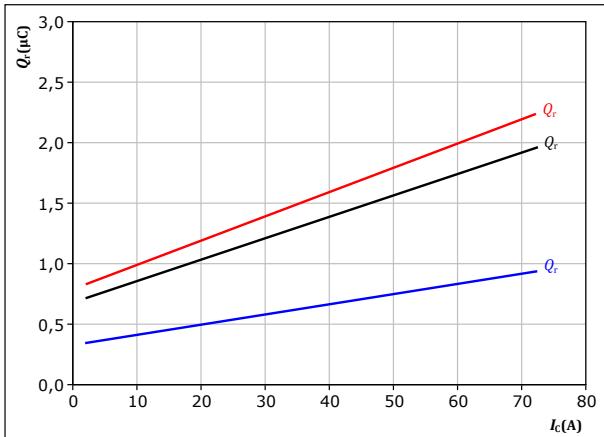
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## Brake Switching Characteristics

figure 43.

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

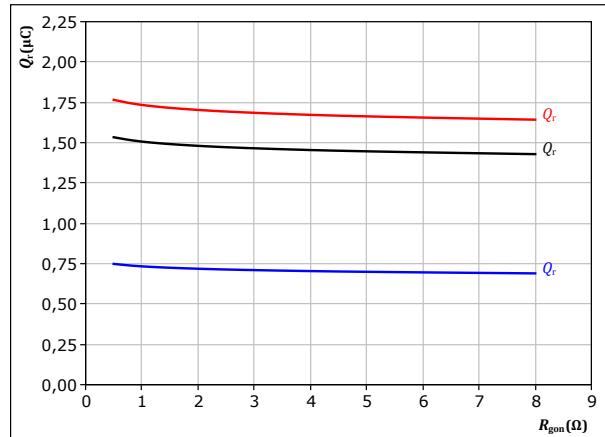
$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

FWD

figure 44.

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

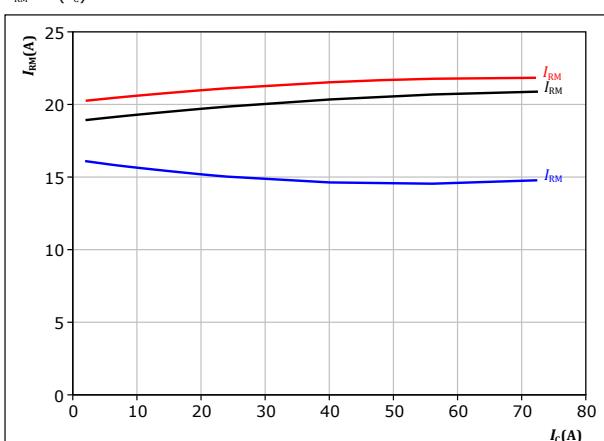
$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ I_c &= 40 \text{ A} \end{aligned}$$

FWD

figure 45.

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

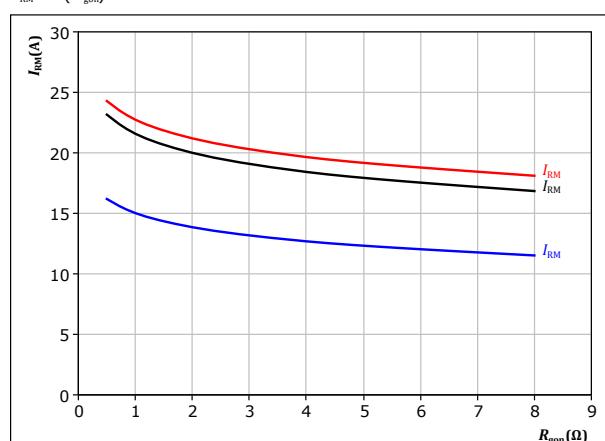
$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

FWD

figure 46.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 400 \text{ V} \\ V_{GE} &= 0/15 \text{ V} \\ I_c &= 40 \text{ A} \end{aligned}$$

FWD

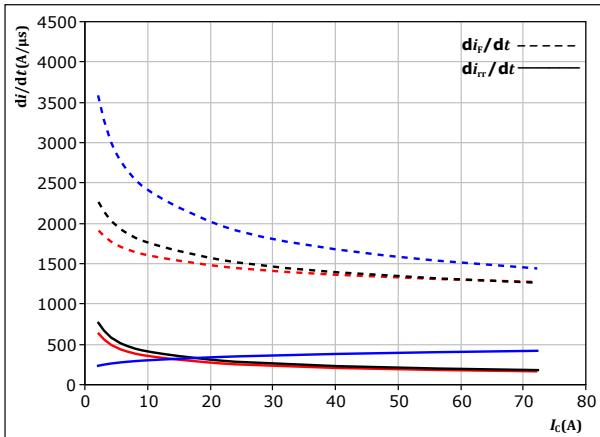


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## Brake Switching Characteristics

figure 47. FWD

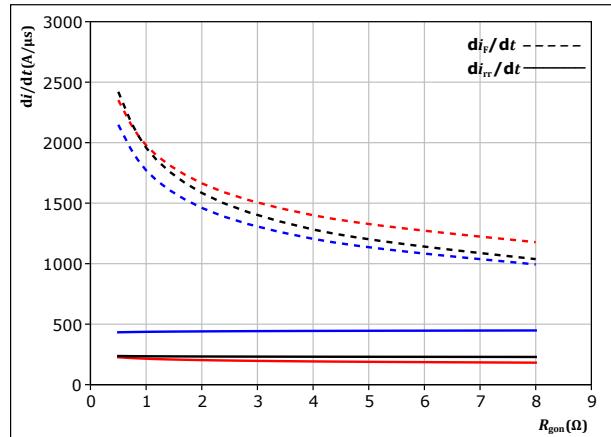
Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at  
 $V_{CE} = 400$  V       $T_j = 25^\circ\text{C}$   
 $V_{GE} = 0/15$  V       $T_j = 125^\circ\text{C}$   
 $R_{gon} = 2$  Ω       $T_j = 150^\circ\text{C}$

figure 48. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$

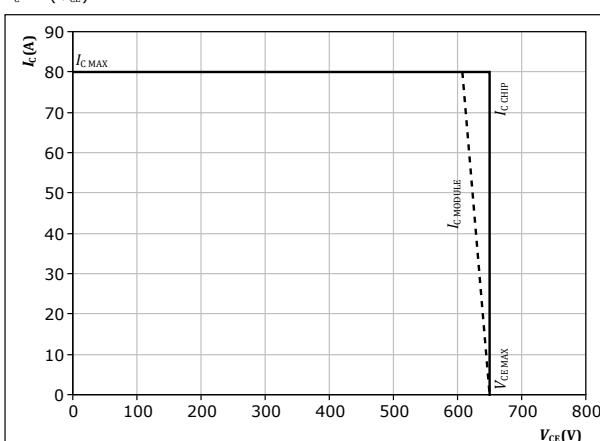


With an inductive load at  
 $V_{CE} = 400$  V       $T_j = 25^\circ\text{C}$   
 $V_{GE} = 0/15$  V       $T_j = 125^\circ\text{C}$   
 $I_c = 40$  A       $T_j = 150^\circ\text{C}$

figure 49. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At       $T_j = 150$  °C  
 $R_{gon} = 2$  Ω  
 $R_{goff} = 2$  Ω



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## Switching Definitions

figure 50. IGBT

Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )

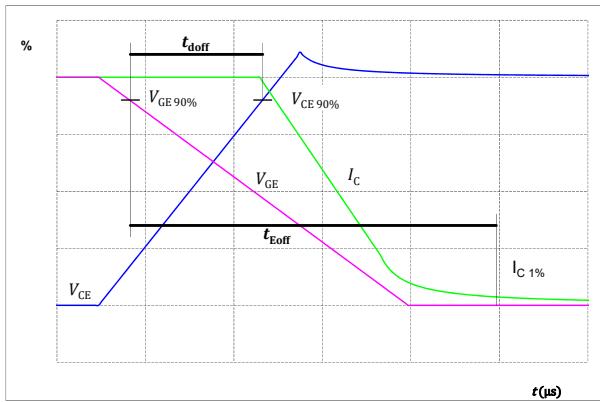


figure 51. IGBT

Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )

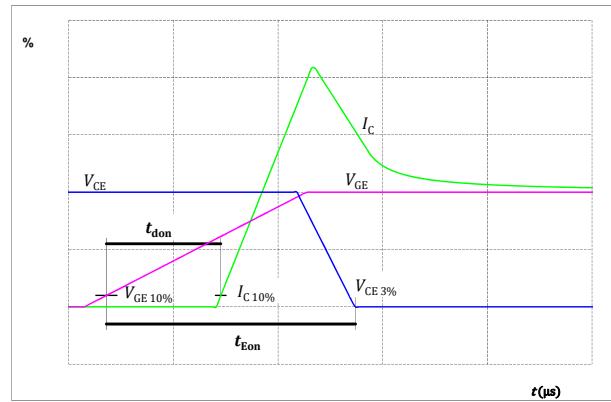


figure 52. IGBT

Turn-off Switching Waveforms & definition of  $t_f$

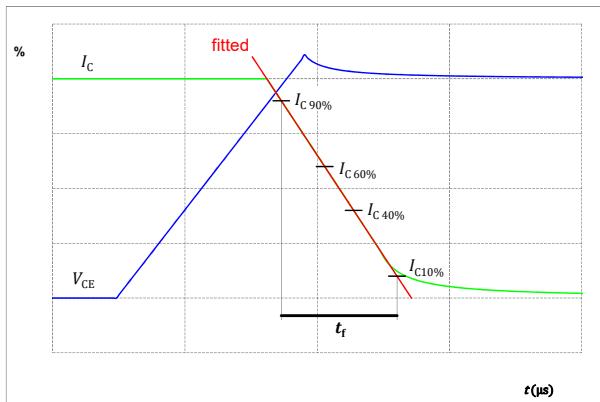
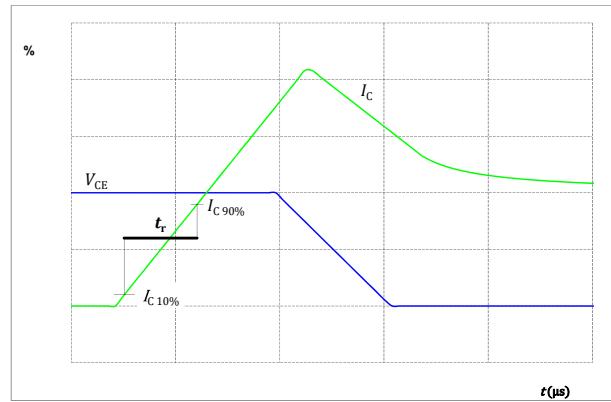


figure 53. IGBT

Turn-on Switching Waveforms & definition of  $t_r$





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## Switching Definitions

figure 54.  
Turn-off Switching Waveforms & definition of  $t_{tr}$

FWD

Turn-off Switching Waveforms & definition of  $t_{tr}$

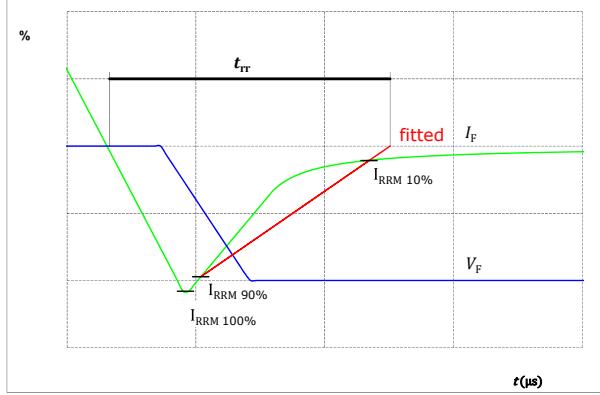
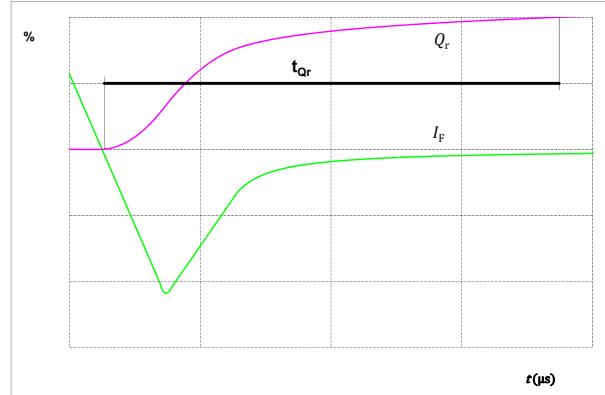


figure 55.  
Turn-on Switching Waveforms & definition of  $t_{qr}$  ( $t_{qr}$  = integrating time for  $Q_r$ )

FWD

Turn-on Switching Waveforms & definition of  $t_{qr}$  ( $t_{qr}$  = integrating time for  $Q_r$ )



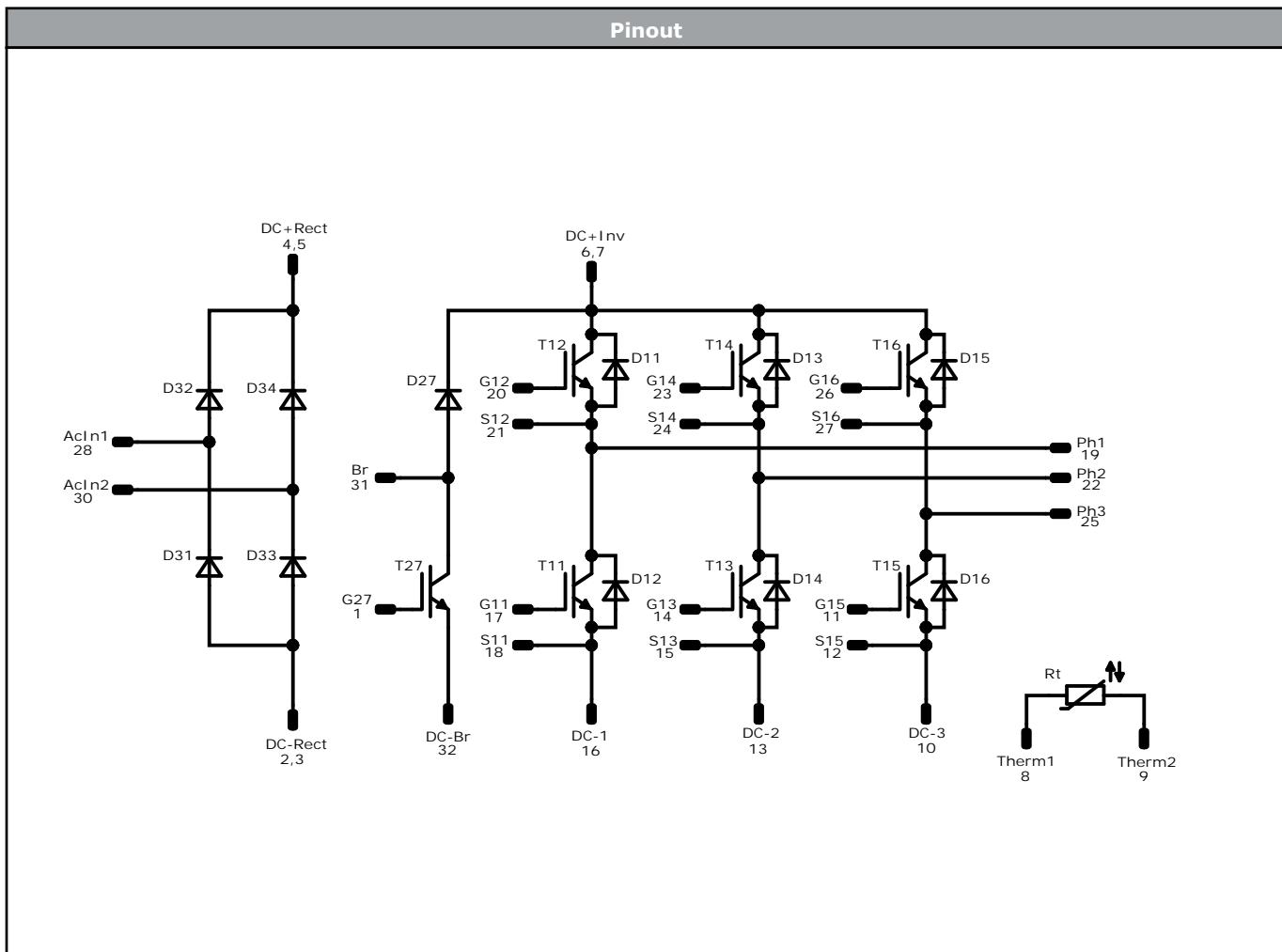


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Ordering Code																																																																																																																																																	
Version			Ordering Code																																																																																																																																														
Without thermal paste			10-PY07PMA040I7-P585B68Y																																																																																																																																														
With thermal paste (5,2 W/mK, PTM6000HV)			10-PY07PMA040I7-P585B68Y-/7/																																																																																																																																														
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 NN-NNNNNNNNNNNNNNNNNN- YYYYYYVV VIN LLLL SSSS	<b>Text</b>	Name NN-NNNNNNNNNNNNNNNN- YYYYYYVV	Date code WWYY	UL & VIN UL VIN	Lot LLLLL																																																																																																																																												
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<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,55</td><td>0</td><td>G27</td></tr><tr><td>2</td><td>47,7</td><td>0</td><td>DC-Rect</td></tr><tr><td>3</td><td>44,8</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td>37,8</td><td>0</td><td>DC+Rect</td></tr><tr><td>5</td><td>37,8</td><td>2,8</td><td>DC+Rect</td></tr><tr><td>6</td><td>35</td><td>0</td><td>DC+Inv</td></tr><tr><td>7</td><td>35</td><td>2,8</td><td>DC+Inv</td></tr><tr><td>8</td><td>28</td><td>0</td><td>Therm1</td></tr><tr><td>9</td><td>25,2</td><td>0</td><td>Therm2</td></tr><tr><td>10</td><td>22,4</td><td>0</td><td>DC-3</td></tr><tr><td>11</td><td>19,6</td><td>0</td><td>G15</td></tr><tr><td>12</td><td>16,8</td><td>0</td><td>S15</td></tr><tr><td>13</td><td>14</td><td>0</td><td>DC-2</td></tr><tr><td>14</td><td>11,2</td><td>0</td><td>G13</td></tr><tr><td>15</td><td>8,4</td><td>0</td><td>S13</td></tr><tr><td>16</td><td>5,6</td><td>0</td><td>DC-1</td></tr><tr><td>17</td><td>2,8</td><td>0</td><td>G11</td></tr><tr><td>18</td><td>0</td><td>0</td><td>S11</td></tr><tr><td>19</td><td>0</td><td>28,5</td><td>Ph1</td></tr><tr><td>20</td><td>2,8</td><td>28,5</td><td>G12</td></tr><tr><td>21</td><td>7,5</td><td>28,5</td><td>S12</td></tr><tr><td>22</td><td>14,5</td><td>28,5</td><td>Ph2</td></tr><tr><td>23</td><td>17,3</td><td>28,5</td><td>G14</td></tr><tr><td>24</td><td>22</td><td>28,5</td><td>S14</td></tr><tr><td>25</td><td>29</td><td>28,5</td><td>Ph3</td></tr><tr><td>26</td><td>31,8</td><td>28,5</td><td>G16</td></tr><tr><td>27</td><td>36,5</td><td>28,5</td><td>S16</td></tr><tr><td>28</td><td>43,5</td><td>28,5</td><td>ACIn1</td></tr><tr><td>29</td><td colspan="3">not assembled</td><td colspan="2"></td></tr><tr><td>30</td><td>52,55</td><td>16,9</td><td>ACIn2</td><td colspan="2"></td></tr><tr><td>31</td><td>52,55</td><td>8,6</td><td>Br</td><td colspan="2"></td></tr><tr><td>32</td><td>52,55</td><td>2,8</td><td>DC-Br</td><td colspan="2" rowspan="2"></td></tr></tbody></table>	Pin	X	Y	Function	1	52,55	0	G27	2	47,7	0	DC-Rect	3	44,8	0	DC-Rect	4	37,8	0	DC+Rect	5	37,8	2,8	DC+Rect	6	35	0	DC+Inv	7	35	2,8	DC+Inv	8	28	0	Therm1	9	25,2	0	Therm2	10	22,4	0	DC-3	11	19,6	0	G15	12	16,8	0	S15	13	14	0	DC-2	14	11,2	0	G13	15	8,4	0	S13	16	5,6	0	DC-1	17	2,8	0	G11	18	0	0	S11	19	0	28,5	Ph1	20	2,8	28,5	G12	21	7,5	28,5	S12	22	14,5	28,5	Ph2	23	17,3	28,5	G14	24	22	28,5	S14	25	29	28,5	Ph3	26	31,8	28,5	G16	27	36,5	28,5	S16	28	43,5	28,5	ACIn1	29	not assembled					30	52,55	16,9	ACIn2			31	52,55	8,6	Br			32	52,55	2,8	DC-Br			<p>center of press-fit pin head, pin head type: PL, plated through hole Ø145 mm +0.09 / -0.06 for further PCB design rules refer to the latest handling instruction</p> <p>159,40 65,405</p>				
Pin	X	Y	Function																																																																																																																																														
1	52,55	0	G27																																																																																																																																														
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4	37,8	0	DC+Rect																																																																																																																																														
5	37,8	2,8	DC+Rect																																																																																																																																														
6	35	0	DC+Inv																																																																																																																																														
7	35	2,8	DC+Inv																																																																																																																																														
8	28	0	Therm1																																																																																																																																														
9	25,2	0	Therm2																																																																																																																																														
10	22,4	0	DC-3																																																																																																																																														
11	19,6	0	G15																																																																																																																																														
12	16,8	0	S15																																																																																																																																														
13	14	0	DC-2																																																																																																																																														
14	11,2	0	G13																																																																																																																																														
15	8,4	0	S13																																																																																																																																														
16	5,6	0	DC-1																																																																																																																																														
17	2,8	0	G11																																																																																																																																														
18	0	0	S11																																																																																																																																														
19	0	28,5	Ph1																																																																																																																																														
20	2,8	28,5	G12																																																																																																																																														
21	7,5	28,5	S12																																																																																																																																														
22	14,5	28,5	Ph2																																																																																																																																														
23	17,3	28,5	G14																																																																																																																																														
24	22	28,5	S14																																																																																																																																														
25	29	28,5	Ph3																																																																																																																																														
26	31,8	28,5	G16																																																																																																																																														
27	36,5	28,5	S16																																																																																																																																														
28	43,5	28,5	ACIn1																																																																																																																																														
29	not assembled																																																																																																																																																
30	52,55	16,9	ACIn2																																																																																																																																														
31	52,55	8,6	Br																																																																																																																																														
32	52,55	2,8	DC-Br																																																																																																																																														
	<p>Tolerance of pin positions: ±0.5mm at the end of pins. Dimension of coordinate axis is only offset without tolerance.</p>																																																																																																																																																



Vincotech



Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	650 V	40 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	650 V	40 A	Inverter Diode	
T27	IGBT	650 V	40 A	Brake Switch	
D27	FWD	650 V	20 A	Brake Diode	
D31, D32, D33, D34	Rectifier	1600 V	35 A	Rectifier Diode	
Rt	Thermistor			Thermistor	

**10-PY07PMA040I7-P585B68Y**

datasheet

# Vincotech

**Packaging instruction**

Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample
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**Handling instruction**

Handling instructions for flow 1 packages see vincotech.com website.

**Package data**

Package data for flow 1 packages see vincotech.com website.

**Vincotech thermistor reference**

See Vincotech thermistor reference table at vincotech.com website.

**UL recognition and file number**

This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition  $T_{j,op}=175^{\circ}\text{C}$  and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-PY07PMA040I7-P585B68Y-D1-14	10 Jun. 2025	Initial Release	

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.